INFORMATION DISCLOSURE CITATION IN AN APPLICATION (Use several sheets if necessary)			Attorney Docket No.: <b>8007-1114</b>		Sheet <u>1</u> of <u>1</u> Application No.: <b>10/588,187</b>		
			Applicant: Hiroki SATO				
			Filing Date: August 2, 2006		Group Art Unit:		
		U.S. PATEN	T DOCUMENTS				
Examiner Initial	Document Number	Date	Name	Class	Subclass	Filing (if appro	date
						***************************************	
		FOREIGN PATE	ENT DOCUMENTS				
Examiner Initial	Document Number	Date	Country	Class	Subclass	Translation	
						Yes	No

## OTHER DOCUMENTS (Including Author, Title, Date, Pertinent Pages, Etc.)

WANG Yong-zhen et al. 1. Lanzhou University, Lanzhou 730000, China 2. Lanzhou Institute of Physics, Lanzhou 73000, China, PREPARATION AND APPLICATION OF SiO2 THIN FILMS, Vacuum & Cryogenics, Vol. 9, pp. 228-233, December, 2003

EXAMINER: DATE CONSIDERED

EXAMINER: Initial if citation considered, whether or not citation is in conformance with MPEP § 609. Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to the applicant.

<sup>\*</sup> Abstract provided for the Examiner's convenience